## Single 2-Input AND Gate

## NL17SG08

The NL17SG08 MiniGate ${ }^{T M}$ is an advanced high-speed CMOS 2-input AND gate in ultra-small footprint.

The NL17SG08 input and output structures provide protection when voltages up to 3.6 V are applied.

## Features

- Designed for 0.9 V to $3.6 \mathrm{~V} \mathrm{~V}_{\mathrm{CC}}$ Operation
- 2.5 ns (Typ) at $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$
- Inputs/Outputs Over-Voltage Tolerant up to 3.6 V
- I Iff Supports Partial Power Down Protection
- Available in SC-88A, SOT-953 and UDFN Packages
- -Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen-Free/BFR-Free and RoHS-Compliant


Figure 1. SOT-953
(Top Thru View)


Figure 2. SC-88A
(Top View)

MARKING DIAGRAMS


UDFN6
$1.45 \times 1.0$ CASE 517AQ

XX = Specific Device Code
M = Date Code*

- = Pb-Free Package
(Note: Microdot may be in either location)
*Date Code orientation and/or position may vary depending upon manufacturing location.

| PIN ASSIGNMENT |  |  |  |
| :---: | :---: | :---: | :---: |
| PIN | SOT-953 | SC-88A | UDFN6 |
| 1 | A | B | B |
| 2 | GND | A | A |
| 3 | B | GND | GND |
| 4 | Y | Y | Y |
| 5 | $\mathrm{~V}_{\mathrm{CC}}$ | $\mathrm{V}_{\mathrm{CC}}$ | NC |
| 6 | - | - | $\mathrm{V}_{\mathrm{CC}}$ |

FUNCTION TABLE

| Inputs |  | Output |
| :---: | :---: | :---: |
| A | B | Y |
| L | L | L |
| L | H | L |
| H | L | L |
| H | H | H |

## ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

Figure 4. Logic Symbol

NL17SG08

Table 1. MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | DC Supply Voltage | -0.5 to +4.3 | V |
| $\mathrm{V}_{\text {IN }}$ | DC Input Voltage | -0.5 to +4.3 | V |
| $\mathrm{V}_{\text {OUT }}$ | DC Output Voltage <br> Active-Mode (High or Low State) <br> Tri-State Mode (Note 1) <br> Power-Down Mode ( $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$ ) | $\begin{gathered} \hline-0.5 \text { to } \mathrm{V}_{\mathrm{CC}}+0.5 \\ -0.5 \text { to }+4.3 \\ -0.5 \text { to }+4.3 \end{gathered}$ | V |
| $\mathrm{IIK}^{\text {I }}$ | DC Input Diode Current $\quad \mathrm{V}_{\mathrm{IN}}<$ GND | -20 | mA |
| IOK | DC Output Diode Current $\quad \mathrm{V}_{\text {OUT }}<$ GND | -20 | mA |
| IOUT | DC Output Source/Sink Current | $\pm 20$ | mA |
| $\mathrm{I}_{\mathrm{CC}}$ or $\mathrm{I}_{\mathrm{GND}}$ | DC Supply Current Per Supply Pin or Ground Pin | $\pm 20$ | mA |
| $\mathrm{T}_{\text {STG }}$ | Storage Temperature Range | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | Lead Temperature, 1 mm from Case for 10 Seconds | 260 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{J}$ | Junction Temperature Under Bias | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\theta_{\mathrm{JA}}$ | $\begin{array}{lr}\text { Thermal Resistance (Note 2) } & \text { SC-88A } \\ \text { SOT-953 } \\ \text { UDFN6 }\end{array}$ | $\begin{aligned} & 377 \\ & 254 \\ & 154 \end{aligned}$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{P}_{\mathrm{D}}$ | $\begin{array}{lr}\text { Power Dissipation in Still Air at } 85^{\circ} \mathrm{C} & \text { SC-88A } \\ & \text { SOT-953 } \\ \\ \text { UDFN6 }\end{array}$ | $\begin{aligned} & 332 \\ & 491 \\ & 812 \end{aligned}$ | mW |
| MSL | Moisture Sensitivity | Level 1 |  |
| $\mathrm{F}_{\mathrm{R}}$ | Flammability Rating Oxygen Index: 28 to 34 | UL 94 V -0 @ 0.125 in |  |
| $\mathrm{V}_{\text {ESD }}$ | ESD Withstand Voltage (Note 3) $\begin{array}{r}\text { Human Body Model } \\ \text { Charged Device Model }\end{array}$ | $\begin{aligned} & 2000 \\ & 1000 \end{aligned}$ | V |
| ILATCHUP | Latchup Performance (Note 4) | $\pm 100$ | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.
2. Measured with minimum pad spacing on an FR4 board, using 10 mm - by - 1inch, 2 ounce copper trace no air flow per JESD51-7.
3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.
4. Tested to EIA/JESD78 Class II.

Table 2. RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter |  | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {CC }}$ | Positive DC Supply Voltage |  | 0.9 | 3.6 | V |
| $\mathrm{V}_{\text {IN }}$ | Digital Input Voltage |  | 0 | 3.6 | V |
| $\mathrm{V}_{\text {OUT }}$ | Output Voltage | Active Mode (High or Low State) Tri-State Mode (Note 1) Power Down Mode ( $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$ ) | $\begin{aligned} & 0 \\ & 0 \\ & 0 \end{aligned}$ | $\begin{gathered} \hline \mathrm{V}_{\mathrm{CC}} \\ 3.6 \\ 3.6 \end{gathered}$ | V |
| $\mathrm{T}_{\mathrm{A}}$ | Operating Free-Air Temperature |  | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{tr}_{\mathrm{r}} \mathrm{t}_{\mathrm{f}}$ | Input Transition Rise or Fall Rate | $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V} \pm 0.3 \mathrm{~V}$ | 0 | 10 | $\mathrm{nS} / \mathrm{V}$ |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Table 3. DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Conditions | $\mathrm{V}_{\mathrm{cc}}(\mathrm{V})$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\mathrm{T}_{\mathrm{A}}=-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max |  |
| $\mathrm{V}_{\mathrm{IH}}$ | High-Level Input Voltage |  | 0.9 | - | $\mathrm{V}_{\mathrm{CC}}$ | - | - | - | V |
|  |  |  | 1.1 to 1.3 | $0.7 \times \mathrm{V}_{\mathrm{CC}}$ | - | - | $0.7 \times \mathrm{V}_{\mathrm{CC}}$ | - |  |
|  |  |  | 1.4 to 1.6 | $0.65 \times \mathrm{V}_{\mathrm{CC}}$ | - | - | $0.65 \times V_{\text {CC }}$ | - |  |
|  |  |  | 1.65 to 1.95 | $0.65 \times \mathrm{V}_{\mathrm{CC}}$ | - | - | $0.65 \times V_{\text {cC }}$ | - |  |
|  |  |  | 2.3 to 2.7 | 1.7 | - | - | 1.7 | - |  |
|  |  |  | 3.0 to 3.6 | 2.0 | - | - | 2.0 | - |  |
| $\mathrm{V}_{\text {IL }}$ | Low-Level Input Voltage |  | 0.9 | - | GND | - | - | - | V |
|  |  |  | 1.1 to 1.3 | - | - | $0.3 \times \mathrm{V}_{\mathrm{CC}}$ | - | $0.3 \times \mathrm{V}_{\mathrm{CC}}$ |  |
|  |  |  | 1.4 to 1.6 | - | - | $0.35 \times V_{\text {CC }}$ | - | $0.35 \times V_{C C}$ |  |
|  |  |  | 1.65 to 1.95 | - | - | $0.35 \times \mathrm{V}_{\mathrm{CC}}$ | - | $0.35 \times \mathrm{V}_{\mathrm{CC}}$ |  |
|  |  |  | 2.3 to 2.7 | - | - | 0.7 | - | 0.7 |  |
|  |  |  | 3.0 to 3.6 | - | - | 0.8 | - | 0.8 |  |
| $\mathrm{V}_{\mathrm{OH}}$ | $\begin{array}{\|c\|} \hline \text { High-Level Output } \\ \text { Voltage } \end{array}$ | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{IH}}$ or $\mathrm{V}_{\mathrm{IL}}$ |  |  |  |  |  |  | V |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-20 \mu \mathrm{~A}$ | 0.9 | - | 0.75 | - | - | - |  |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-0.3 \mathrm{~mA}$ | 1.1 to 1.3 | $0.75 \times \mathrm{V}_{\text {cC }}$ | - | - | $0.75 \times \mathrm{V}_{\mathrm{CC}}$ | - |  |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-1.7 \mathrm{~mA}$ | 1.4 to 1.6 | $0.75 \times \mathrm{V}_{\mathrm{CC}}$ | - | - | $0.75 \times \mathrm{V}_{\mathrm{CC}}$ | - |  |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-3.0 \mathrm{~mA}$ | 1.65 to 1.95 | $\mathrm{V}_{\text {cC }}-0.45$ | - | - | $\mathrm{V}_{\mathrm{CC}}-0.45$ | - |  |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-4.0 \mathrm{~mA}$ | 2.3 to 2.7 | 2.0 | - | - | 2.0 | - |  |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-8.0 \mathrm{~mA}$ | 3.0 to 3.6 | 2.48 | - | - | 2.48 | - |  |
| V OL | Low-Level Output Voltage | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{IH}}$ or $\mathrm{V}_{\mathrm{IL}}$ |  |  |  |  |  |  | V |
|  |  | $\mathrm{I}_{\mathrm{OL}}=20 \mu \mathrm{~A}$ | 0.9 | - | 0.1 | - | - | - |  |
|  |  | $\mathrm{l}_{\mathrm{OL}}=0.3 \mathrm{~mA}$ | 1.1 to 1.3 | - | - | $0.25 \times \mathrm{V}_{\mathrm{CC}}$ | - | $0.25 \times \mathrm{V}_{\mathrm{CC}}$ |  |
|  |  | $\mathrm{I}_{\mathrm{OL}}=1.7 \mathrm{~mA}$ | 1.4 to 1.6 | - | - | $0.25 \times \mathrm{V}_{\mathrm{CC}}$ | - | $0.25 \times \mathrm{V}_{\mathrm{CC}}$ |  |
|  |  | $\mathrm{l}_{\mathrm{OL}}=3.0 \mathrm{~mA}$ | 1.65 to 1.95 | - | - | 0.45 | - | 0.45 |  |
|  |  | $\mathrm{l}_{\mathrm{OL}}=4.0 \mathrm{~mA}$ | 2.3 to 2.7 | - | - | 0.4 | - | 0.4 |  |
|  |  | $\mathrm{I}_{\mathrm{OL}}=8.0 \mathrm{~mA}$ | 2.7 to 3.6 | - | - | 0.4 | - | 0.4 |  |
| $\mathrm{I}_{\mathrm{IN}}$ | Input Leakage Current | $\mathrm{V}_{\text {IN }}=0 \mathrm{~V}$ to 3.6 V | 0.9 to 3.6 | - | - | $\pm 0.1$ | - | $\pm 1.0$ | $\mu \mathrm{A}$ |
| IOFF | Power Off Leakage Current | $\begin{aligned} & \mathrm{V}_{\text {IN }}=0 \mathrm{~V} \text { to } 3.6 \mathrm{~V} ; \\ & \mathrm{V}_{\text {OUT }}=0 \mathrm{~V} \text { to } 3.6 \mathrm{~V} \end{aligned}$ | 0 | - | - | 1.0 | - | 10.0 | $\mu \mathrm{A}$ |
| ${ }^{\text {cc }}$ | Quiescent Supply Current Current | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}}$ or GND | 0.9 to 3.6 | - | - | 1.0 | - | 10.0 | $\mu \mathrm{A}$ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Table 4. AC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Condition | $\mathrm{V}_{\mathrm{cc}}(\mathrm{V})$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\begin{gathered} \mathrm{T}_{\mathrm{A}}= \\ -55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \end{gathered}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max |  |
| $t_{\text {PLH }}$, $t_{\text {PHL }}$ | Propagation Delay, (A or B) to Y <br> (Figures 5 and 6) | $\begin{aligned} \mathrm{C}_{\mathrm{L}} & =10 \mathrm{pF} \\ \mathrm{R}_{\mathrm{L}} & =1 \mathrm{M} \Omega \end{aligned}$ | 0.9 | - | 46.5 | - | - | - | ns |
|  |  |  | 1.1 to 1.3 | - | 14.1 | 26.7 | - | 31.7 |  |
|  |  |  | 1.4 to 1.6 | - | 5.9 | 9.6 | - | 11.3 |  |
|  |  |  | 1.65 to 1.95 | - | 4.5 | 7.0 | - | 7.5 |  |
|  |  |  | 2.3 to 2.7 | - | 2.9 | 4.4 | - | 4.9 |  |
|  |  |  | 3.0 to 3.6 | - | 2.2 | 3.5 | - | 4.1 |  |
|  |  | $\begin{aligned} \mathrm{C}_{\mathrm{L}} & =15 \mathrm{pF} \\ \mathrm{R}_{\mathrm{L}} & =1 \mathrm{M} \Omega \end{aligned}$ | 0.9 | - | 47.9 | - | - | - | ns |
|  |  |  | 1.1 to 1.3 | - | 14.4 | 27.3 | - | 32.4 |  |
|  |  |  | 1.4 to 1.6 | - | 6.5 | 9.5 | - | 12.6 |  |
|  |  |  | 1.65 to 1.95 | - | 5.0 | 7.7 | - | 8.0 |  |
|  |  |  | 2.3 to 2.7 | - | 3.2 | 4.9 | - | 5.6 |  |
|  |  |  | 3.0 to 3.6 | - | 2.5 | 3.8 | - | 4.4 |  |
|  |  | $\begin{gathered} \mathrm{C}_{\mathrm{L}}=30 \mathrm{pF} \\ \mathrm{R}_{\mathrm{L}}=1 \mathrm{M} \Omega \end{gathered}$ | 0.9 | - | 52.5 | - | - | - | ns |
|  |  |  | 1.1 to 1.3 | - | 15.3 | 29.3 | - | 34.7 |  |
|  |  |  | 1.4 to 1.6 | - | 8.9 | 11.8 | - | 14.9 |  |
|  |  |  | 1.65 to 1.95 | - | 6.9 | 10.3 | - | 10.8 |  |
|  |  |  | 2.3 to 2.7 | - | 4.4 | 6.4 | - | 6.8 |  |
|  |  |  | 3.0 to 3.6 | - | 3.5 | 4.9 | - | 5.4 |  |

Table 5. CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Test Condition | Typical $\left(\mathbf{T}_{\mathbf{A}}=\mathbf{2 5}{ }^{\circ} \mathbf{C}\right)$ | Unit |
| :---: | :--- | :--- | :---: | :---: |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$ | 3.0 | pF |
| $\mathrm{C}_{\mathrm{PD}}$ | Power Dissipation <br> Capacitance (Note 5) | $\mathrm{f}=10 \mathrm{MHz}, \mathrm{V}_{\mathrm{CC}}=0.9 \mathrm{~V}$ to $3.6 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{CC}}$ | 4.0 | pF |

5. $\mathrm{C}_{P D}$ is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation $\mathrm{I}_{\mathrm{CC}(\mathrm{OPR})}=\mathrm{C}_{\mathrm{PD}} \cdot \mathrm{V}_{\mathrm{CC}} \cdot \mathrm{f}_{\mathrm{in}}+\mathrm{I}_{\mathrm{CC}} . \mathrm{C}_{\mathrm{PD}}$ is used to determine the no-load dynamic power consumption: $\mathrm{P}_{\mathrm{D}}=\mathrm{C}_{\mathrm{PD}} \cdot \mathrm{V}_{\mathrm{CC}}{ }^{2} \cdot \mathrm{f}_{\mathrm{in}}+\mathrm{I}_{\mathrm{CC}} \cdot \mathrm{V}_{\mathrm{CC}}$.

$\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance
$R_{T}$ is $Z_{\text {OUT }}$ of pulse generator (typically 50 W ) $\mathrm{f}=1 \mathrm{MHz}$

Figure 5. Test Circuit


Figure 6. Switching Waveforms

| $\mathbf{V}_{\mathbf{C c}}, \mathbf{V}$ | $\mathbf{V}_{\mathbf{m i}}, \mathbf{V}$ | $\mathbf{V}_{\mathbf{m o}}, \mathbf{V}$ | $\mathbf{V}_{\mathbf{Y}}, \mathbf{V}$ |
| :---: | :---: | :---: | :---: |
| 0.9 | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 0.1 |
| 1.1 to 1.3 | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 0.1 |
| 1.4 to 1.6 | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 0.1 |
| 1.65 to 1.95 | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 0.15 |
| 2.3 to 2.7 | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 0.15 |
| 3.0 to 3.6 | 1.5 | 1.5 | 0.3 |

ORDERING INFORMATION

| Device | Marking | Pin 1 Orientation <br> (See below) | Package | Shipping $^{\dagger}$ |
| :--- | :---: | :---: | :---: | :---: |
| NL17SG08DFT2G | AT | Q4 | SC-88A | $3000 /$ Tape \& Reel |
| NL17SG08DFT2G-Q* | AT | Q4 | SC-88A | $3000 /$ Tape \& Reel |
| NL17SG08P5T5G | Y | Q2 | SOT-953 | $8000 /$ Tape \& Reel |
| NL17SG08MU1TCG | L (Rotated $\left.180^{\circ} \mathrm{CW}\right)$ | Q4 | UDFN6 $1.45 \times 1.0$ | $3000 /$ Tape \& Reel |
| NL17SG08MU3TCG | L (Rotated $90^{\circ} \mathrm{CW}$ ) | Q4 | UDFN6 $1.0 \times 1.0$ | $3000 /$ Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

PIN 1 ORIENTATION IN TAPE AND REEL Direction of Feed



## SC-88A (SC-70-5/SOT-353)

CASE 419A-02
ISSUE M
DATE 11 APR 2023


RECDMMENDED
MIUNTING FGUTPRINT

* For additional information on our Pb -Free strategy and soldering details, please download the aN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

NDTES:

1. DIMENSIDNING AND TQLERANCING PER ANSI Y14.5M, 1982.
2. CDNTRZLLING DIMENSIDN: MILLIMETERS
3. 419A-01 BBSOLETE, NEW STANDARD 419A-02
4. DIMENSIDNS D AND E1 D NDT INCLUDE MULD FLASH, PRDTRUSIUNS, $\square R$ GATE BURRS, MLLD FLASH, PRDTRUSIINS, GR GATE BURRS SHALL NDT EXCEED $0.1016 M M$ PER SIDE.

| DIM | MILLIMETERS |  |  |
| :---: | :---: | :---: | :---: |
|  | MIN. | NIM. | MAX. |
| A | 0.80 | 0.95 | 1.10 |
| A1 | --- | --- | 0.10 |
| A3 | 0.20 REF |  |  |
| b | 0.10 | 0.20 | 0.30 |
| $\subset$ | 0.10 | --- | 0.25 |
| D | 1.80 | 2.00 | 2.20 |
| E | 2.00 | 2.10 | 2.20 |
| E1 | 1.15 | 1.25 | 1.35 |
| e | 0.65 BSC |  |  |
| L | 0.10 | 0.15 | 0.30 |

## GENERIC MARKING

 DIAGRAM*
*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-$ Free indicator, " G " or microdot " r ", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code
$\mathrm{M}=$ Date Code

- = Pb-Free Package
(Note: Microdot may be in either location)


PIN 1. BASE
2. EMITTER
. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 6:
$\begin{array}{lc}\text { TYLE 6: } & \text { STYLE 7: } \\ \text { PIN 1. EMITTER } 2 & \text { PIN 1. BASE } \\ \text { 2. BASE } 2 & \text { 2. EMITTER } \\ \text { 3. EMITTER 1 } & \text { 3. BASE } \\ \text { 4. COLLECTOR } & \text { 4. COLLECTOR } \\ \text { 5. COLLECTOR 2/BASE } 1 & \text { 5. COLLECTOR }\end{array}$
STYLE 2 :
PIN 1. ANODE
2. EMITTER
3. BASE
4. COLLECTOR

STYLE 3:
STYLE 3:
PIN 1. ANODE 1
2. $N / C$
2. N/C
3. ANODE
4. CATHODE 2
5. CATHODE 1

## STYLE 8

## PIN 1. CATHODE

2. COLLECTOR
3. $\mathrm{N} / \mathrm{C}$
4. BASE
. EMITTER

STYLE 5:
STYLE 4:
2. DRAIN $1 / 2$

PIN 1. CATHODE
$\begin{array}{ll}\text { 2. DRAIN } 1 / 2 & \text { 2. COMMON ANODE } \\ \text { 3. SOURCE } 1 & \text { 3. }\end{array}$
3. SOURCE 1 3. CATHODE 2
4. GATE 1 4. CATHODE 3
5. GATE 2

## STYLE 9:

PIN 1. ANODE
2. CATHODE
3. ANODE
4. ANODE
5. ANODE

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

| DOCUMENT NUMBER: | 98ASB42984B | Electronic versions are uncontrolled except when accessed directly from the Document Repository. <br> Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| :--- | :--- | :--- |

DESCRIPTION: $\quad$ SC-88A (SC-70-5/SOT-353)
PAGE 1 OF 1

[^0]UDFN6, 1.45x1.0, 0.5P CASE 517AQ

ISSUE O
DATE 15 MAY 2008


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
CONTROLLING DIMENSION: MILLIMETERS
2. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.


DETAIL B OPTIONAL CONSTRUCTIONS

## MOUNTING FOOTPRINT



DIMENSIONS: MILLIMETERS
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## GENERIC

MARKING DIAGRAM*


X = Specific Device Code
M = Date Code
*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-$ Free indicator, "G" or microdot " $\quad$ ", may or may not be present.

| DOCUMENT NUMBER: | 98AON30313E | Electronic versions are uncontrolled except when accessed directly from the Document Repository. <br> Printed versions are uncontroled except when stamped "CONTROLLED COPY" in red. |
| ---: | :--- | :--- | :--- |
| DESCRIPTION: | UDFN6, 1.45x1.0, 0.5P | PAGE 1 OF 1 |

[^1]UDFN6, 1x1, 0.35P
CASE 517BX
ISSUE O
DATE 18 MAY 2011

*For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-$ Free indicator, " G " or microdot " $\mathrm{\nabla}$ ", may or may not be present. Some products may not follow the Generic Marking.

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| ---: | :--- | :--- | :--- |
| DESCRIPTION: | UDFN6, 1x1, 0.35P |  | PAGE 1 OF 1 |

[^2]
## SOT-953 1.00x0.80x0.37, 0.35P <br> CASE 527AE <br> ISSUE F

DATE 17 JAN 2024

NDTES

1. DIMENSIUNING AND TZLERANCING PER ASME Y14.5M, 2018,
2. CZNTRDLLING DIMENSIDN: MILLIMETERS,
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS पF THE BASE MATERIAL
4. DIMENSIDNS D AND E DI NDT INCLUDE MDLD FLASH, PRITRUSIINS, IR GATE BURRS.


SIDE VIEW


RECDMMENDED MIUNTING FOUTPRINT
*For additional information on our Pb-Free strategy and soldering details, please download the ZN Semiconductor Soldering and Mounting Techniques Reference Manual, SaLDERRM/D.

MARKING DIAGRAM*


X = Specific Device Code
M = Month Code
*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-\mathrm{Free}$ indicator, " G " or microdot " P ", may or may not be present. Some products may not follow the Generic Marking.

| MILLIMETERS |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | NDM | MAX |  |
| A | 0.34 | 0.37 | 0.40 |  |
| $b$ | 0.10 | 0.15 | 0.20 |  |
| C | 0.07 | 0.12 | 0.17 |  |
| D | 0.95 | 1.00 | 1.05 |  |
| $E$ | 0.75 | 0.80 | 0.85 |  |
| $e$ | 0.35 BSC |  |  |  |
| $H$ | 0.95 | 1.00 | 1.05 |  |
| $L$ | 0.125 | 0.175 | 0.225 |  |
| L2 | 0.05 | 0.10 | 0.15 |  |
| L3 | 0.075 (REF) |  |  |  |

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